

Total No. of Questions :4]

SEAT No. :

P1872

[5323]-56

[Total No. of Pages : 2

M.Sc. - II (Inorganic Chemistry)
CH - 431 : MATERIAL SCIENCE
(2008 Pattern) (Semester - IV)

Time : 3 Hours]

[Max. Marks : 80

Instructions to the candidates:

- 1) All questions are compulsory.*
- 2) Neat diagrams must be drawn wherever necessary.*
- 3) Figures to the right indicate full marks.*
- 4) Use of logarithmic table and calculator is allowed.*

Q1) Attempt any **FOUR** of the following :

[20]

- a) What is diffusion? Explain the types of diffusion mechanism in solids.
- b) Derive the expression $X = \frac{C}{T - \theta}$.
- c) Describe the different layers in the cross section of a tree stem with function of each layer.
- d) Explain the types of superconductors.
- e) What are Biomaterials? How they are classified?

Q2) Attempt any **FOUR** of the following :

[20]

- a) What is Portland cement? What are different types of Portland cement?
- b) What are nanomaterials? Name the various methods for synthesis of nanomaterials. Why these methods are important?
- c) What are the different types of magnetism?
- d) What is concrete? How it is prepared? Explain proportion of concrete mixture.
- e) What is Luminescence? Explain different types of Luminescences.

P.T.O.

Q3) Solve any **FOUR** of the following : **[20]**

- a) Saturation magnetisation of FCC Iron is 1700 kA/m^2 . Calculate the net magnetic moment per Iron atom in crystal. Given lattice parameter of FCC Iron is 2.87 \AA .
- b) Calculate the energy gap in Silicon given that it is transparent to radiation of wavelength greater than 11000 \AA .
- c) Mobility of electrons and holes in sample of intrinsic Ge at room temperature are $3600 \text{ cm}^2/\text{Vsec}$ and $1700 \text{ cm}^2/\text{Vsec}$. respectively. If electron and hole densities are equal to $2.5 \times 10^{13} / \text{cm}^3$. Calculate the conductivity.
- d) In an n-type semiconductor the fermi level lies 0.3 eV below the conduction band at room temperature. If the temperature is increased at 330 K . Find the position of fermi level. [Room temp. = 300 K].
- e) In 'Si' energy gap is 0.75 eV . What is wavelength at which start absorption of light?

Q4) Write a short note on any **FOUR** : **[20]**

- a) Working of n-p junction
- b) Ferroelectrical materials
- c) Glass transition temperature
- d) Photoconductivity
- e) Macrodefect free cement

